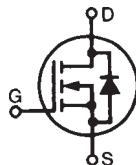


## Linear L2™ Power MOSFET w/ Extended FBSOA

### IXTK200N10L2 IXTX200N10L2

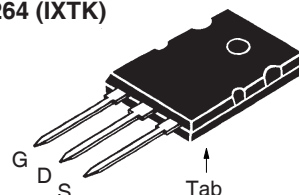
$V_{DSS} = 100V$   
 $I_{D25} = 200A$   
 $R_{DS(on)} \leq 11m\Omega$

N-Channel Enhancement Mode  
 Guaranteed FBSOA  
 Avalanche Rated

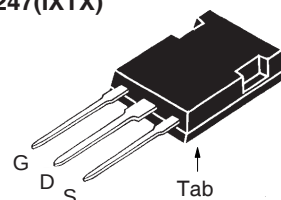


| Symbol     | Test Conditions                                           | Maximum Ratings   |            |
|------------|-----------------------------------------------------------|-------------------|------------|
| $V_{DSS}$  | $T_J = 25^\circ C$ to $150^\circ C$                       | 100               | V          |
| $V_{DGR}$  | $T_J = 25^\circ C$ to $150^\circ C$ , $R_{GS} = 1M\Omega$ | 100               | V          |
| $V_{GSS}$  | Continuous                                                | $\pm 20$          | V          |
| $V_{GSM}$  | Transient                                                 | $\pm 30$          | V          |
| $I_{D25}$  | $T_C = 25^\circ C$ (Chip Capability)                      | 200               | A          |
| $I_{LRMS}$ | Lead Current Limit, (RMS)                                 | 160               | A          |
| $I_{DM}$   | $T_C = 25^\circ C$ , Pulse Width Limited by $T_{JM}$      | 500               | A          |
| $I_A$      | $T_C = 25^\circ C$                                        | 100               | A          |
| $E_{AS}$   | $T_C = 25^\circ C$                                        | 5                 | J          |
| $P_D$      | $T_C = 25^\circ C$                                        | 1040              | W          |
| $T_J$      |                                                           | -55...+150        | $^\circ C$ |
| $T_{JM}$   |                                                           | 150               | $^\circ C$ |
| $T_{stg}$  |                                                           | -55...+150        | $^\circ C$ |
| $T_L$      | 1.6mm (0.063 in.) from Case for 10s                       | 300               | $^\circ C$ |
| $T_{SOLD}$ | Plastic Body for 10s                                      | 260               | $^\circ C$ |
| $M_d$      | Mounting Torque (IXTK)                                    | 1.13/10           | Nm/lb.in.  |
| $F_C$      | Mounting Force (IXTX)                                     | 20..120 / 4.5..27 | N/lb.      |
| Weight     | TO-264                                                    | 10                | g          |
|            | PLUS247                                                   | 6                 | g          |

TO-264 (IXTK)



PLUS247(IXTX)



G = Gate      D = Drain  
 S = Source    Tab = Drain

### Features

- Designed for Linear Operation
- Avalanche Rated
- Guaranteed FBSOA at  $75^\circ C$

### Advantages

- Easy to Mount
- Space Savings
- High Power Density

### Applications

- Solid State Circuit Breakers
- Soft Start Controls
- Linear Amplifiers
- Programmable Loads
- Current Regulators

| Symbol       | Test Conditions<br>( $T_J = 25^\circ C$ , Unless Otherwise Specified) | Characteristic Values |      |                           |
|--------------|-----------------------------------------------------------------------|-----------------------|------|---------------------------|
|              |                                                                       | Min.                  | Typ. | Max.                      |
| $BV_{DSS}$   | $V_{GS} = 0V$ , $I_D = 1mA$                                           | 100                   |      | V                         |
| $V_{GS(th)}$ | $V_{DS} = V_{GS}$ , $I_D = 3mA$                                       | 2.0                   |      | 4.5 V                     |
| $I_{GSS}$    | $V_{GS} = \pm 20V$ , $V_{DS} = 0V$                                    |                       |      | $\pm 200$ nA              |
| $I_{DSS}$    | $V_{DS} = V_{DSS}$ , $V_{GS} = 0V$<br>$T_J = 125^\circ C$             |                       |      | 10 $\mu A$<br>250 $\mu A$ |
| $R_{DS(on)}$ | $V_{GS} = 10V$ , $I_D = 0.5 \cdot I_{D25}$ , Note 1                   |                       |      | 11 m $\Omega$             |

| Symbol       | Test Conditions<br>( $T_J = 25^\circ\text{C}$ , Unless Otherwise Specified)                                                                        | Characteristic Values |      |                    |
|--------------|----------------------------------------------------------------------------------------------------------------------------------------------------|-----------------------|------|--------------------|
|              |                                                                                                                                                    | Min.                  | Typ. | Max.               |
| $g_{fs}$     | $V_{DS} = 10\text{V}$ , $I_D = 60\text{A}$ , Note 1                                                                                                | 55                    | 73   | 90 S               |
| $C_{iss}$    | $V_{GS} = 0\text{V}$ , $V_{DS} = 25\text{V}$ , $f = 1\text{MHz}$                                                                                   |                       | 23   | nF                 |
| $C_{oss}$    |                                                                                                                                                    |                       | 3200 | pF                 |
| $C_{rss}$    |                                                                                                                                                    |                       | 610  | pF                 |
| $t_{d(on)}$  | <b>Resistive Switching Times</b><br>$V_{GS} = 10\text{V}$ , $V_{DS} = 0.5 \cdot V_{DSS}$ , $I_D = 0.5 \cdot I_{D25}$<br>$R_G = 1\Omega$ (External) |                       | 40   | ns                 |
| $t_r$        |                                                                                                                                                    |                       | 225  | ns                 |
| $t_{d(off)}$ |                                                                                                                                                    |                       | 127  | ns                 |
| $t_f$        |                                                                                                                                                    |                       | 27   | ns                 |
| $Q_{g(on)}$  | $V_{GS} = 10\text{V}$ , $V_{DS} = 0.5 \cdot V_{DSS}$ , $I_D = 0.5 \cdot I_{D25}$                                                                   |                       | 540  | nC                 |
| $Q_{gs}$     |                                                                                                                                                    |                       | 115  | nC                 |
| $Q_{gd}$     |                                                                                                                                                    |                       | 226  | nC                 |
| $R_{thJC}$   |                                                                                                                                                    |                       | 0.12 | $^\circ\text{C/W}$ |
| $R_{thCS}$   |                                                                                                                                                    | 0.15                  |      | $^\circ\text{C/W}$ |

## Safe-Operating-Area Specification

| Symbol | Test Conditions                                                                              | Characteristic Values |      |      |
|--------|----------------------------------------------------------------------------------------------|-----------------------|------|------|
|        |                                                                                              | Min.                  | Typ. | Max. |
| SOA    | $V_{DS} = 100\text{V}$ , $I_D = 6.25\text{A}$ , $T_C = 75^\circ\text{C}$ , $t_p = 5\text{s}$ | 625                   |      | W    |

## Source-Drain Diode

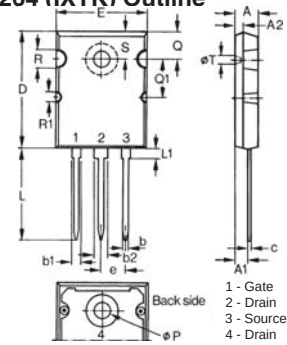
| Symbol   | Test Conditions<br>( $T_J = 25^\circ\text{C}$ , Unless Otherwise Specified)                             | Characteristic Values |      |               |
|----------|---------------------------------------------------------------------------------------------------------|-----------------------|------|---------------|
|          |                                                                                                         | Min.                  | Typ. | Max.          |
| $I_S$    | $V_{GS} = 0\text{V}$                                                                                    |                       |      | 200 A         |
| $I_{SM}$ | Repetitive, Pulse Width Limited by $T_{JM}$                                                             |                       |      | 800 A         |
| $V_{SD}$ | $I_F = 100\text{A}$ , $V_{GS} = 0\text{V}$ , Note 1                                                     |                       |      | 1.4 V         |
| $t_{rr}$ | $I_F = 100\text{A}$ , $-di/dt = 100\text{A}/\mu\text{s}$ ,<br>$V_R = 50\text{V}$ , $V_{GS} = 0\text{V}$ |                       | 245  | ns            |
| $I_{RM}$ |                                                                                                         |                       | 24.4 | A             |
| $Q_{RM}$ |                                                                                                         |                       | 3.0  | $\mu\text{C}$ |

Note 1. Pulse test,  $t \leq 300\mu\text{s}$ , duty cycle,  $d \leq 2\%$ .

## ADVANCE TECHNICAL INFORMATION

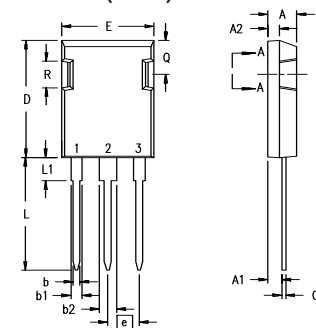
The product presented herein is under development. The Technical Specifications offered are derived from a subjective evaluation of the design, based upon prior knowledge and experience, and constitute a "considered reflection" of the anticipated result. IXYS reserves the right to change limits, test conditions, and dimensions without notice.

## TO-264 (IXTK) Outline



| Dim. | Millimeter |       | Inches   |       |
|------|------------|-------|----------|-------|
|      | Min.       | Max.  | Min.     | Max.  |
| A    | 4.82       | 5.13  | .190     | .202  |
| A1   | 2.54       | 2.89  | .100     | .114  |
| A2   | 2.00       | 2.10  | .079     | .083  |
| b    | 1.12       | 1.42  | .044     | .056  |
| b1   | 2.39       | 2.69  | .094     | .106  |
| b2   | 2.90       | 3.09  | .114     | .122  |
| c    | 0.53       | 0.83  | .021     | .033  |
| D    | 25.91      | 26.16 | 1.020    | 1.030 |
| E    | 19.81      | 19.96 | .780     | .786  |
| e    | 5.46 BSC   |       | .215 BSC |       |
| J    | 0.00       | 0.25  | .000     | .010  |
| K    | 0.00       | 0.25  | .000     | .010  |
| L    | 20.32      | 20.83 | .800     | .820  |
| L1   | 2.29       | 2.59  | .090     | .102  |
| P    | 3.17       | 3.66  | .125     | .144  |
| Q    | 6.07       | 6.27  | .239     | .247  |
| Q1   | 8.38       | 8.69  | .330     | .342  |
| R    | 3.81       | 4.32  | .150     | .170  |
| R1   | 1.78       | 2.29  | .070     | .090  |
| S    | 6.04       | 6.30  | .238     | .248  |
| T    | 1.57       | 1.83  | .062     | .072  |

## PLUS 247™ (IXTX) Outline



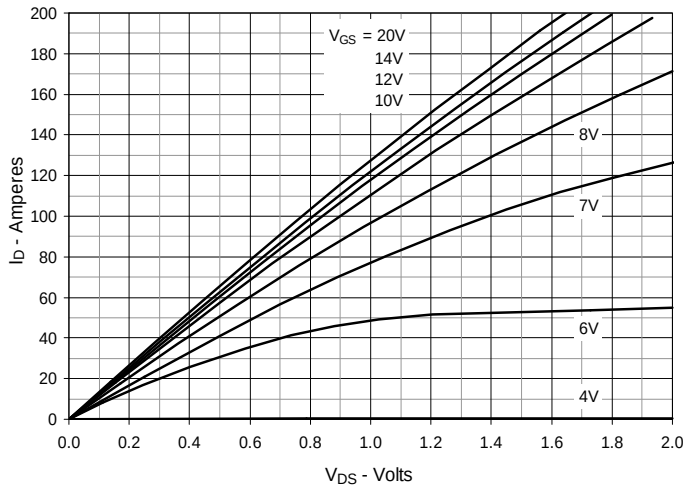
Terminals: 1 - Gate  
2 - Drain  
3 - Source

| Dim.           | Millimeter |       | Inches   |      |
|----------------|------------|-------|----------|------|
|                | Min.       | Max.  | Min.     | Max. |
| A              | 4.83       | 5.21  | .190     | .205 |
| A <sub>1</sub> | 2.29       | 2.54  | .090     | .100 |
| A <sub>2</sub> | 1.91       | 2.16  | .075     | .085 |
| b              | 1.14       | 1.40  | .045     | .055 |
| b <sub>1</sub> | 1.91       | 2.13  | .075     | .084 |
| b <sub>2</sub> | 2.92       | 3.12  | .115     | .123 |
| C              | 0.61       | 0.80  | .024     | .031 |
| D              | 20.80      | 21.34 | .819     | .840 |
| E              | 15.75      | 16.13 | .620     | .635 |
| e              | 5.45 BSC   |       | .215 BSC |      |
| L              | 19.81      | 20.32 | .780     | .800 |
| L1             | 3.81       | 4.32  | .150     | .170 |
| Q              | 5.59       | 6.20  | .220     | .244 |
| R              | 4.32       | 4.83  | .170     | .190 |

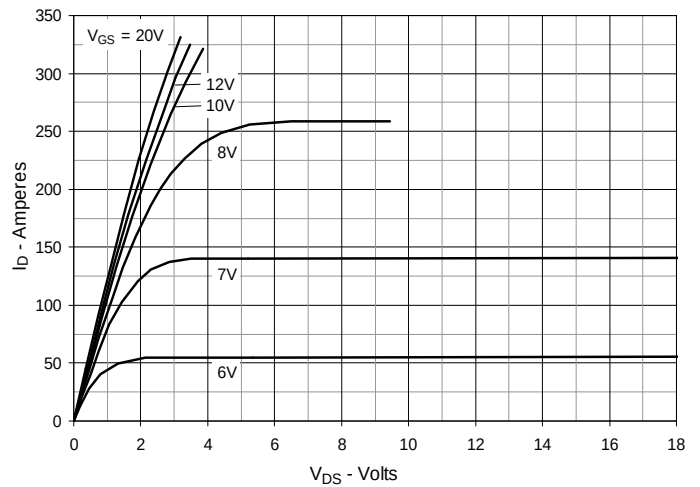
IXYS Reserves the Right to Change Limits, Test Conditions, and Dimensions.

|                                                                                  |           |           |           |           |              |              |              |              |              |             |
|----------------------------------------------------------------------------------|-----------|-----------|-----------|-----------|--------------|--------------|--------------|--------------|--------------|-------------|
| IXYS MOSFETs and IGBTs are covered by one or more of the following U.S. patents: | 4,835,592 | 4,931,844 | 5,049,961 | 5,237,481 | 6,162,665    | 6,404,065 B1 | 6,683,344    | 6,727,585    | 7,005,734 B2 | 7,157,338B2 |
|                                                                                  | 4,850,072 | 5,017,508 | 5,063,307 | 5,381,025 | 6,259,123 B1 | 6,534,343    | 6,710,405 B2 | 6,759,692    | 7,063,975 B2 |             |
|                                                                                  | 4,881,106 | 5,034,796 | 5,187,117 | 5,486,715 | 6,306,728 B1 | 6,583,505    | 6,710,463    | 6,771,478 B2 | 7,071,537    |             |

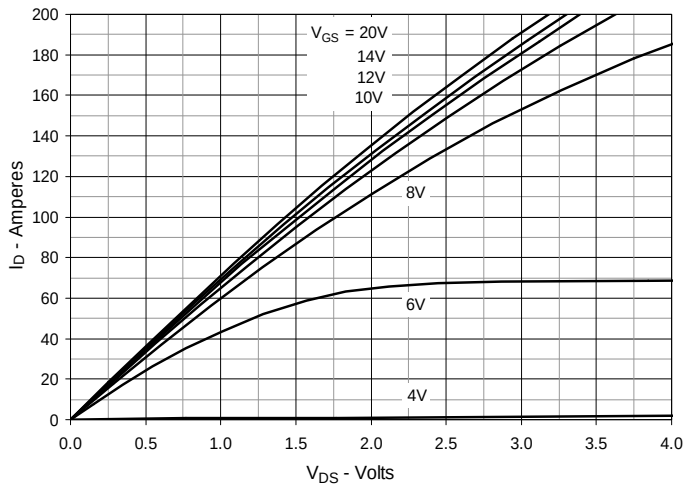
**Fig. 1. Output Characteristics @  $T_J = 25^\circ\text{C}$**



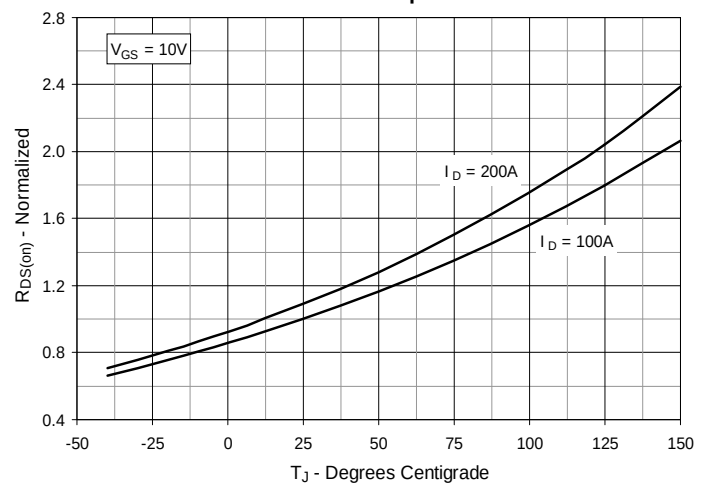
**Fig. 2. Extended Output Characteristics @  $T_J = 25^\circ\text{C}$**



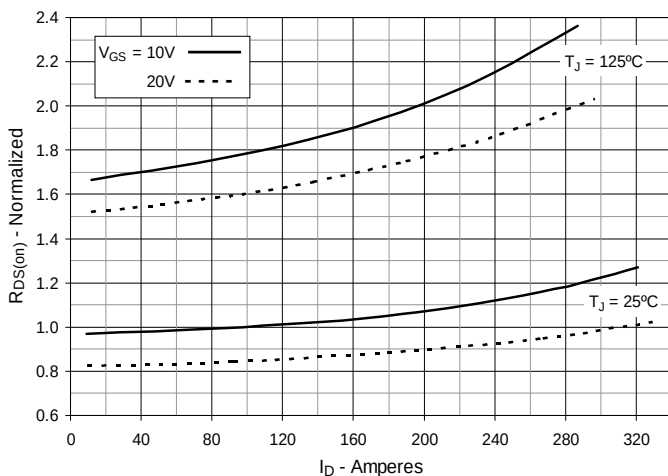
**Fig. 3. Output Characteristics @  $T_J = 125^\circ\text{C}$**



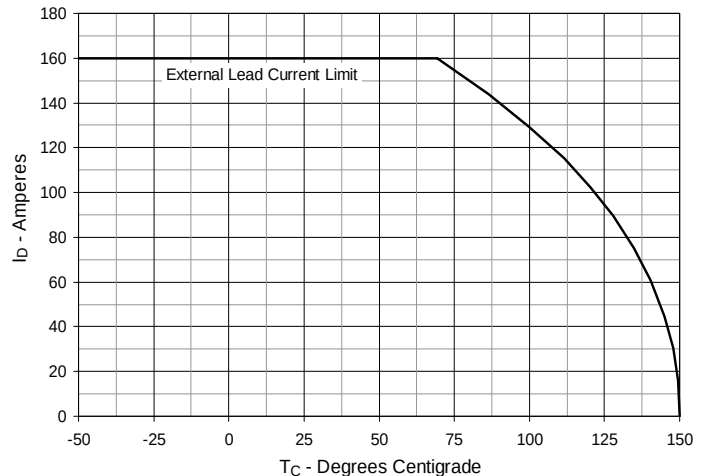
**Fig. 4.  $R_{DS(on)}$  Normalized to  $I_D = 100\text{A}$  Value vs. Junction Temperature**



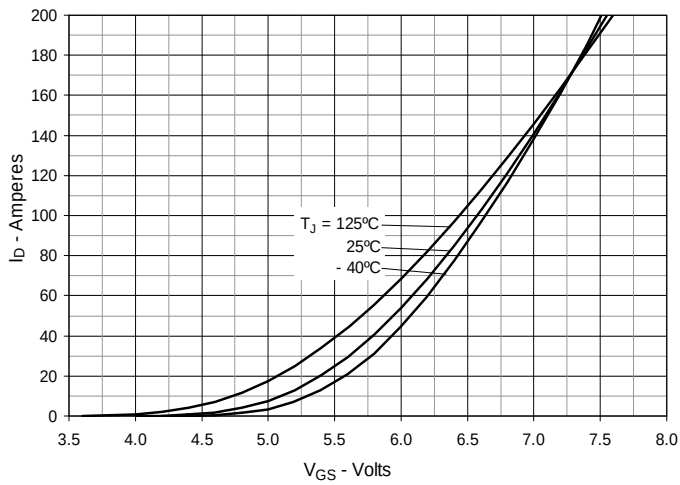
**Fig. 5.  $R_{DS(on)}$  Normalized to  $I_D = 100\text{A}$  Value vs. Drain Current**



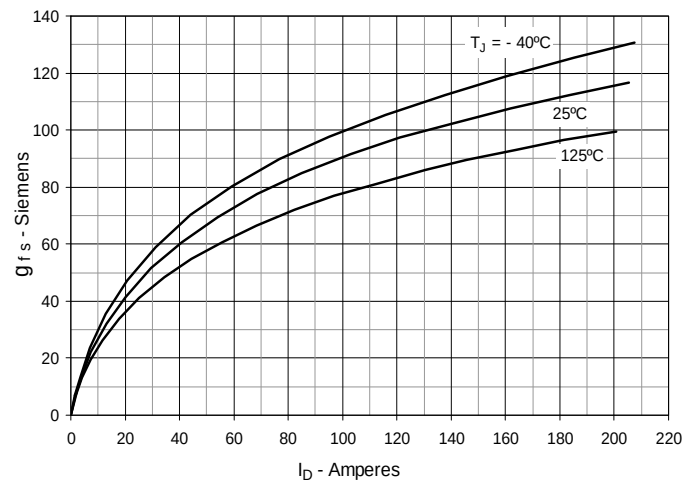
**Fig. 6. Maximum Drain Current vs. Case Temperature**



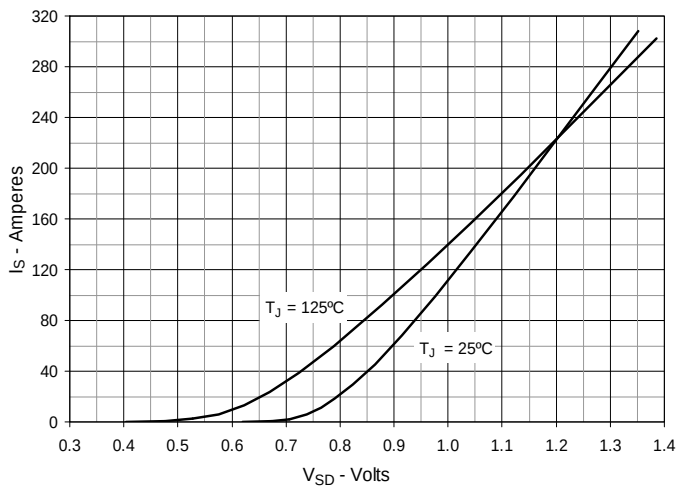
**Fig. 7. Input Admittance**



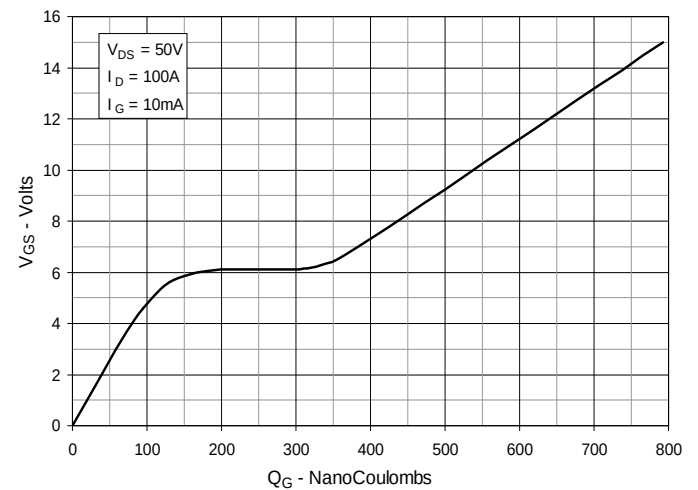
**Fig. 8. Transconductance**



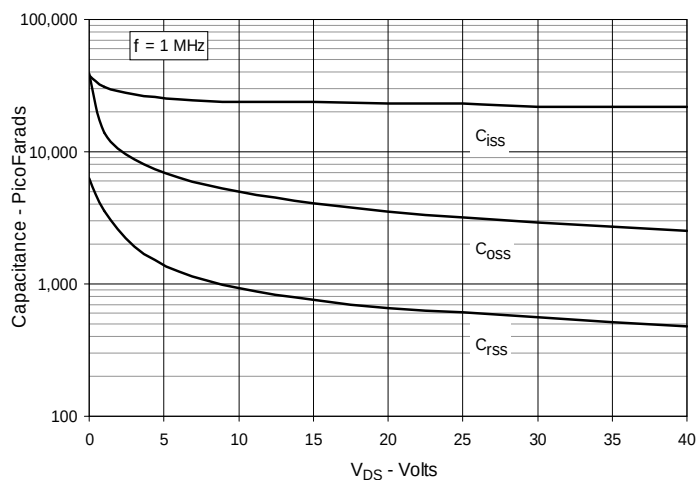
**Fig. 9. Forward Voltage Drop of Intrinsic Diode**



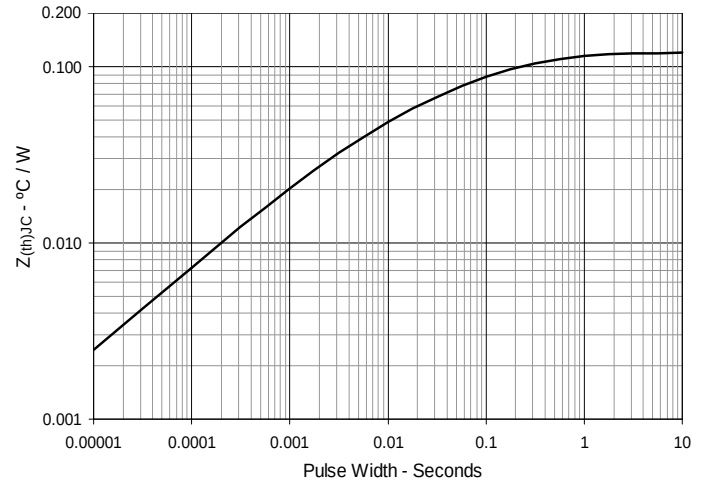
**Fig. 10. Gate Charge**



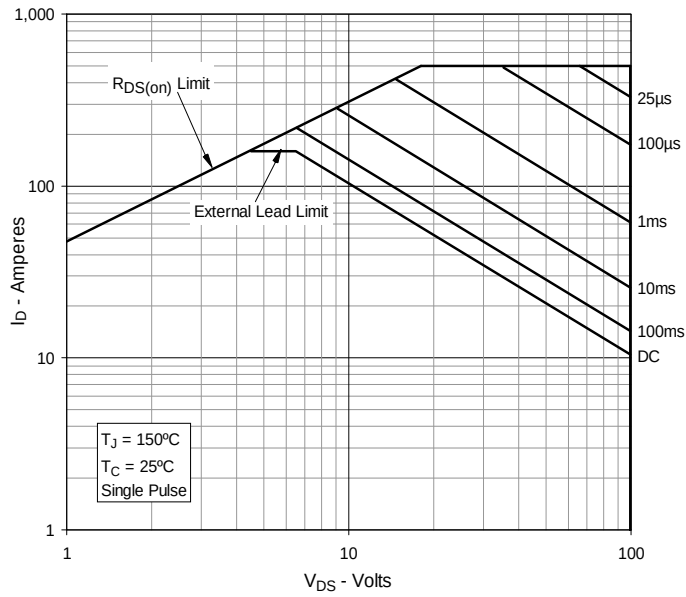
**Fig. 11. Capacitance**



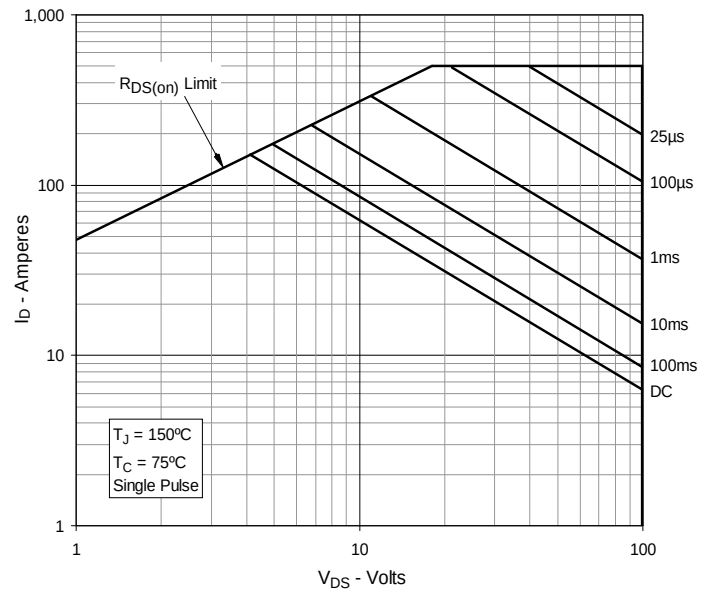
**Fig. 12. Maximum Transient Thermal Impedance**



**Fig. 13. Forward-Bias Safe Operating Area**  
**@  $T_C = 25^\circ\text{C}$**



**Fig. 14. Forward-Bias Safe Operating Area**  
**@  $T_C = 75^\circ\text{C}$**





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